

	Type	Hits	Search Text	DBs
1	BRS	1	<b>10/731018</b>	<b>US- PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB</b>
2	BRS	1	<b>functional ADJ film and S1</b>	<b>US- PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB</b>
3	BRS	<b>1717</b>	<b>349/113</b>	<b>US- PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB</b>
4	BRS	<b>1772</b>	<b>349/43</b>	<b>US- PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB</b>

	Type	Hits	Search Text	DBs
5	BRS	757	<b>349/38</b>	<b>US- PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB</b>
6	BRS	42	<b>S3 and S4 and S5</b>	<b>US- PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB</b>
7	BRS	1	<b>10/731018</b>	<b>US- PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB</b>
8	BRS	4	<b>light ADJ (shield\$3 block\$3) ADJ insulat\$3 ADJ (layer film) with (SiN silicon ADJ nitride SiON silicon ADJ oxide ADJ nitride)</b>	<b>US- PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB</b>

	Type	Hits	Search Text	DBs
9	BRS	4	<b>light ADJ (shield\$3 block\$3) ADJ insulat\$3 ADJ (layer film) same (SiN silicon ADJ nitride SiON silicon ADJ oxide ADJ nitride)</b>	<b>US- PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB</b>
10	BRS	1119	<b>light ADJ (shield\$3 block\$3) same (SiN silicon ADJ nitride SiON silicon ADJ oxide ADJ nitride)</b>	<b>US- PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB</b>
11	BRS	492	<b>light ADJ (shield\$3 block\$3) with (SiN silicon ADJ nitride SiON silicon ADJ oxide ADJ nitride)</b>	<b>US- PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB</b>
12	BRS	1976	<b>large ADJ dielectric ADJ constant</b>	<b>US- PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB</b>

	Type	Hits	Search Text	DBs
13	BRS	16	<b>S11 and S12</b>	<b>US- PGPUB; USPAT; EPO; JPO; DERWENT ; IBM_TDB</b>